

Features

- Lead free versions available
- RoHS compliant (lead free version)*
- New Product Development
- Integrated Passive Device
- ESD Protection to IEC61000-4-2 Spec.

2FAH-C20R Series - Integrated Passive & Active Device using CSP

General Information

This application specific integrated passive component is designed to provide all of the necessary ESD protection and line resistance required on the data port of a custom portable electronic device. The ESD protection provided by the component enables the data port to withstand ±8 KV Contact / ±15 KV Air Discharge when tested according to the method specified in IEC 61000-4-2. The component incorporates 7 identical channels and is supplied in a 20 pin CSP package which is intended to be mounted directly onto an FR4 printed circuit board. This package will meet typical thermal cycle and bend test specifications without the use of an underfill material.

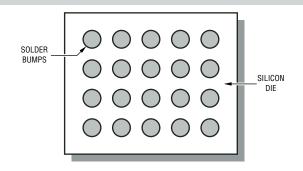


Figure 1 - CSP Format

Electrical & Thermal Characteristics

| Electrical Characteristics | Symbol | Minimum | Nominal | Maximum | Unit |
|---|------------------|-----------------|---------|---------------|-------|
| (T _A = 25 °C unless otherwise noted) | Syllibol | IVIIIIIIIIIIIII | Nonnia | IVIAAIIIIUIII | Offic |
| Zener Diode | | | | | |
| Breakdown Voltage @ 1 mA | V_{BR} | 6 | 7.2 | 8 | V |
| Leakage Current @ 3 V | I _R | | | 1 | μA |
| ESD Performance (Note 1) | | | | | |
| Withstand | | | | | |
| Contact Discharge | | ±8 | | | kV |
| Air Discharge | | ±15 | | | kV |
| Let Through (Note 2) | | | | | |
| Contact Discharge | | | | ±150 | V |
| Air Discharge | | | | ±150 | V |
| Channel Specification | | | | | |
| Resistance | R | 90 | 100 | 110 | Ω |
| Capacitance @ 1 V & 1 MHz | С | 8.5 | 10.5 | 12.5 | pF |
| Thermal Characteristics | | | | | |
| (T _A = 25 °C unless otherwise noted) | | | | | |
| Operating Temperature | TJ | -40 | 25 | +85 | °C |
| Storage Temperature | T _{stq} | -60 | 25 | +125 | °C |
| Total Power Dissipation @ 70 °C | P _D | | | 100 | mW |

Note:

- 1. The IEC 61000-4-2 test method will be adapted for component level testing. The device will provide the specified ESD protection performance on the "IN 1-7" pins only.
- 2. "Let Through" is a measure of the component of an incident ESD transient that the protection device allows through to the down stream circuitry.

Mechanical Characteristics

This is a Silicon-based device and is packaged using chip scale packaging technology. Solder bumps, formed on the Silicon die, provide the interconnect medium from die to PCB. The bumps are arranged on the die in a regular grid formation. The grid pitch is 0.5mm. The dimensions for the CSP packaged device are shown in Fig. 2 below.

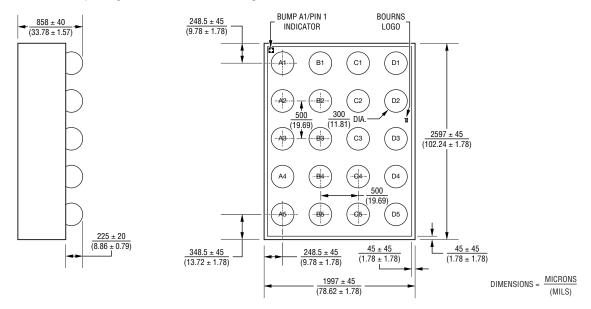


Fig. 2 - Device Mechanical Drawing

Reliability

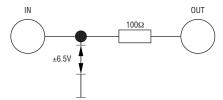
Reliability data exists and continues to be gathered on an ongoing basis for Bourns Integrated Passive and Active Devices using CSP packaging.

"Package level" testing of the integrity of the solder joint is carried out on an independent Daisy-Chain test device. A 25-Pin Daisy Chain component is available from Bourns for this purpose (part number 2TAD-C25R). This is a 5 x 5 array featuring 0.5mm pitch solder bumps. The Distance to Neutral Point (DNP) on that component is larger than that of the 2FAH-C20R and is thus deemed a worse case for Thermal Cycle testing.

"Silicon level" reliability performance will be assured by similarity to other Integrated Passive and Active Devices using CSP product from Bourns.

Individual Channel Schematic

This section contains the schematic (See Fig. 3 below) for the single channel in the integrated passive device. Note that the electrical parameters of primary interest are (a) DC Resistance and (b) ESD performance. In terms of DC parameters it should be noted that all resistor values have a tolerance of ± 10 %. This schematic consists of a series 100ohm resistance and Back to Back Zener 6.5 Volt diodes for ESD protection.



Key Design Parameters

DC Channel Resistance: 100 Ω ±10 %

DC Channel Capacitance: 12.5 pF Maximum

 V_{BR} : 6 V Min, 8 V Max @ I_{BR} = 1 mA.

 I_R : 1 uA Max @ V_R =3 V.

Fig. 3 - Channel Schematic

Block Diagram

Figure 4 contains a block diagram of the CSP device. This diagram includes the pin names and basic electrical connections associated with each channel.

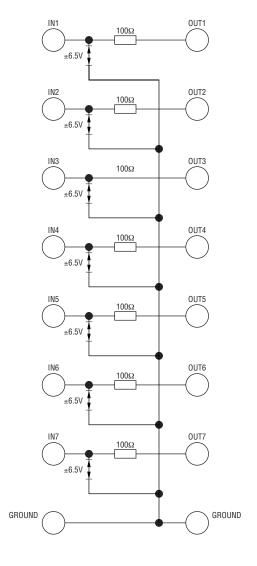


Fig. 4 - Device Block Diagram

Marking

The device will be laser marked on the backside according to the following Fig. 5 scheme below. Position A1, on the Bump Grid is located at the top left of the die when the die is orientated so that the mark is read in the normal fashion.

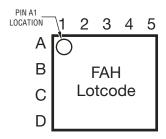
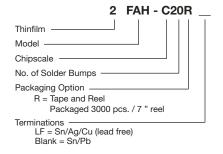


Fig. 5 - Backside Laser Mark

PCB Design and SMT Processing

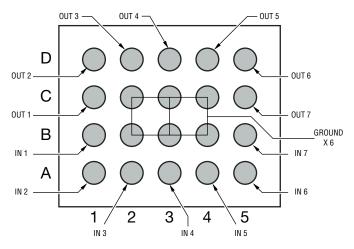
Please consult Bourns' *Thin Film on Silicon using CSP* Users Guide Application Note for notes on PCB design and SMT processing.

How to Order



Device Pin Out

The Pin-Out for the device is shown in Fig. 6. Note also that the device is shown with bumps facing up.



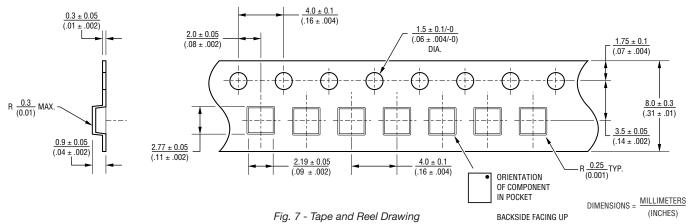
| Function | Pin Out | Function | Pin Out |
|----------|---------|----------|---------|
| IN1 | B1 | OUT4 | D3 |
| IN2 | A1 | OUT5 | D4 |
| IN3 | A2 | OUT6 | D5 |
| IN4 | A3 | OUT7 | C5 |
| IN5 | A4 | Ground | B2 |
| IN6 | A5 | Ground | B3 |
| IN7 | B5 | Ground | B4 |
| OUT1 | C1 | Ground | C2 |
| OUT2 | D1 | Ground | C3 |
| OUT3 | D2 | Ground | C4 |

Fig. 6 (a) - Device Pin Out "Bumps Up" View

Fig. 6 (b) - Pin Listings

Packaging

The product will be dispensed in an 8mm x 4mm Tape and Reel format - see Fig. 7 diagram below. The Tape and Reel package will conform to customer specification.





Reliable Electronic Solutions

Asia-Pacific: TEL +886- (0)2 25624117 • FAX +886- (0)2 25624116

Europe: TEL +353 214 515 225 • FAX +353 214 515 292 **The Americas:** TEL +1-951 781-5492 • FAX +1-951 781-5700

www.bourns.com